

Click to view price, real time Inventory, Delivery & Lifecycle Information ;

NCV317MABSTT3G

onsemi

Switching Voltage Regulators ANA 500MA ADJUST OUT VOLTAGE REGULATOR

Any questions, please feel free to contact us. info@kaimte.com

Voltage Regulator -Adjustable Output, Positive

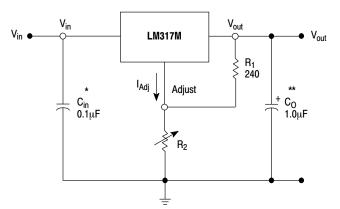
DUU MA The LM317M is

The LM317M is an adjustable three-terminal positive voltage regulator capable of supplying in excess of 500 mA over an output voltage range of 1.2 V to 37 V. This voltage regulator is exceptionally easy to use and requires only two external resistors to set the output voltage. Further, it employs internal current limiting, thermal shutdown and safe area compensation, making it essentially blow-out proof.

The LM317M serves a wide variety of applications including local, on-card regulation. This device also makes an especially simple adjustable switching regulator, a programmable output regulator, or by connecting a fixed resistor between the adjustment and output, the LM317M can be used as a precision current regulator.

Features

- Output Current in Excess of 500 mA
- Output Adjustable between 1.2 V and 37 V
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Floating Operation for High Voltage Applications
- Eliminates Stocking Many Fixed Voltages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices



* = C_{in} is required if regulator is located an appreciable distance from power supply filter. ** = C_0 is not needed for stability, however, it does improve transient response.

$$V_{out} = 1.25 V \left(1 + \frac{R_2}{R_1}\right) + I_{Adj} R_2$$

Since I_{Adj} is controlled to less than 100 μ A, the error associated with this term is negligible in most applications.

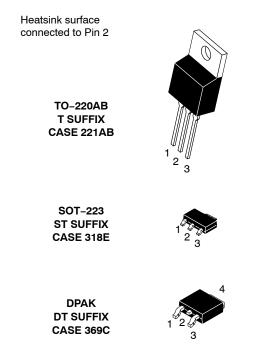
Figure 1. Simplified Application

Semiconductor Components Industries, LLC, 2014 October, 2019 – Rev. 26



ON Semiconductor®

www.onsemi.com



Heatsink Surface (shown as terminal 4 in case outline drawing) is connected to Pin 2.

PIN ASSIGNMENT				
1	Adjust			
2	V _{out}			
3	V _{in}			

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 11 of this data sheet.

MAXIMUM RATINGS ($T_A = 25^{\circ}C$, unless otherwise noted.)

Rating	Symbol	Value	Unit
Input-Output Voltage Differential	V _I –V _O	40	Vdc
Power Dissipation (Package Limitation) (Note 1)			
Plastic Package, T Suffix, Case 221A			
$T_A = 25^{\circ}C$	PD	Internally Limited	
Thermal Resistance, Junction-to-Air	AL^{Θ}	70	°C/W
Thermal Resistance, Junction-to-Case	θ _{JC}	5.0	°C/W
Plastic Package, DT Suffix, Case 369C			
$T_A = 25^{\circ}C$	PD	Internally Limited	
Thermal Resistance, Junction-to-Air	AL^{Θ}	92	°C/W
Thermal Resistance, Junction-to-Case	θ _{JC}	5.0	°C/W
Plastic Package, ST Suffix, Case 318E			
$T_A = 25^{\circ}C$	PD	Internally Limited	
Thermal Resistance, Junction-to-Air	θ_{JA}	245	°C/W
Thermal Resistance, Junction-to-Case	θ_{JC}	15	°C/W
Maximum Junction Temperature	T _{JMAX}	+150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Figure 25 provides thermal resistance versus PC board pad size.

ELECTRICAL CHARACTERISTICS ($V_I - V_O = 5.0 \text{ V}$; $I_O = 0.1 \text{ A}$, $T_J = T_{low}$ to T_{high} (Note 2), unless otherwise noted.)

			LM317M	/LM317MB/NC	V317MB	
Characteristics	Figure	Symbol	Min	Тур	Max	Unit
Line Regulation (Note 3) (T _A = 25°C, 3.0 V \leq V _I – V _O \leq 40 V)	3	Reg _{line}	-	0.01	0.04	%/V
Load Regulation (Note 3) $T_A = 25^{\circ}C$, 10 mA $\leq I_O \leq 0.5$ A $V_O \leq 5.0$ V $V_O \geq 5.0$ V	4	Reg _{load}		5.0 0.1	25 0.5	mV % V _O
Adjustment Pin Current	5	I _{Adi}	-	50	100	μA
Adjustment Pin Current Change 2.5 V \leq V _I – V _O \leq 40 V, 10 mA \leq I _L \leq 0.5 A, P _D \leq P _{max}	3, 4	Δl _{Adj}	-	0.2	5.0	μΑ
Reference Voltage 3.0 V \leq VI – V_O \leq 40 V, 10 mA \leq IL \leq 0.5 A, P_D \leq P_max	5	V _{ref}	1.20	1.25	1.30	V
Line Regulation 3.0 V \leq V _I -V _O \leq 40 V (Note 3)	3	Reg _{line}	-	0.02	0.07	%/V
Load Regulation 10 mA \leq I_O \leq 0.5 A (Note 3) $V_O \leq$ 5.0 V $V_O \geq$ 5.0 V	4	Reg _{load}	-	20 0.3	70 1.5	mV % V _O
Temperature Stability ($T_{low} \le T_J \le T_{high}$)	5	T _S	-	0.7	-	% V _O
Minimum Load Current to Maintain Regulation ($V_I - V_O = 40 V$)	5	I _{Lmin}	-	3.5	10	mA
$ \begin{array}{l} \mbox{Maximum Output Current} \\ V_I - V_O \leq 15 \mbox{ V, } P_D \leq P_{max} \\ V_I - V_O = 40 \mbox{ V, } P_D \leq P_{max}, T_A = 25^{\circ} C \end{array} $	5	I _{max}	0.5 0.15	0.9 0.25		A
RMS Noise, % of V_O (T_A = 25°C, 10 Hz \leq f \leq 10 kHz)	-	N	-	0.003	-	% V _O
Ripple Rejection, V _O = 10 V, f = 120 Hz (Note 4) Without C_{Adj} $C_{Adj} = 10 \ \mu F$	6	RR	_ 66	65 80	-	dB
Thermal Shutdown (Note 5)	-	-	-	180	-	°C
Long–Term Stability, $T_J = T_{high}$ (Note 6) $T_A = 25^{\circ}C$ for End–point Measurements	5	S	-	0.3	1.0	%/1.0 kHrs.

2. T_{low} to $T_{high} = 0^{\circ}$ to +125°C for LM317M T_{low} to $T_{high} = -40^{\circ}$ to +125°C for LM317MB, NCV317MB.3. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account

separately. Pulse testing with low duty cycle is used.
C_{Adj}, when used, is connected between the adjustment pin and ground.
Thermal characteristics are not subject to production test.
Since Long-Term Stability cannot be measured on each device before shipment, this specification is an engineering estimate of average stability form let the later. stability from lot-to-lot.

			LM317MA/LM317MAB/NCV317MA		CV317MAB	
Characteristics	Figure	Symbol	Min	Тур	Max	Unit
Line Regulation (Note 8) (T_A = 25°C, 3.0 V \leq VI – VO \leq 40 V)	3	Reg _{line}	-	0.01	0.04	%/V
Load Regulation (Note 8) $\begin{split} T_A &= 25^\circ C, \ 10 \ mA \leq I_O \leq 0.5 \ A \\ V_O &\leq 5.0 \ V \\ V_O &\geq 5.0 \ V \end{split}$	4	Reg _{load}		5.0 0.1	25 0.5	mV % V ₍
Adjustment Pin Current	5	I _{Adj}	-	50	100	μA
Adjustment Pin Current Change 2.5 V \leq V _I $-$ V _O \leq 40 V, 10 mA \leq I _L \leq 0.5 A, P _D \leq P _{max}	3, 4	Δl _{Adj}	-	0.2	5.0	μA
Reference Voltage 3.0 V \leq V _I $-$ V _O \leq 40 V, 10 mA \leq I _L \leq 0.5 A, P _D \leq P _{max}	5	V _{ref}	1.225	1.250	1.275	V
Line Regulation (Note 8) 3.0 V \leq V _I -V _O \leq 40 V	3	Reg _{line}	-	0.02	0.07	%/\
Load Regulation (Note 8) 10 mA $\leq I_O \leq 0.5$ A $V_O \leq 5.0$ V $V_O \geq 5.0$ V	4	Reg _{load}	- -	20 0.3	70 1.5	mV % V
Temperature Stability $(T_{low} \le T_J \le T_{high})$	5	Τ _S	-	0.7	-	% V(
Minimum Load Current to Maintain Regulation ($V_I - V_O = 40 V$)	5	I _{Lmin}	-	3.5	10	mA
$ \begin{array}{l} \mbox{Maximum Output Current} \\ V_I - V_O \leq 15 \ V, \ P_D \leq P_{max} \\ V_I - V_O = 40 \ V, \ P_D \leq P_{max}, \ T_A = 25^\circ C \end{array} $	5	I _{max}	0.5 0.15	0.9 0.25	-	A
RMS Noise, % of V _O (T _A = 25°C, 10 Hz \leq f \leq 10 kHz)	-	N	-	_	-	% V(
Ripple Rejection, V_O = 10 V, f = 120 Hz (Note 9) Without C_{Adj} C_{Adj} = 10 μF	6	RR	_ 66	65 80	-	dB
Thermal Shutdown (Note 10)	-	-	-	180	-	°C
Long-Term Stability, $T_J = T_{high}$ (Note 11) $T_A= 25^{\circ}C$ for End-point Measurements	5	S	-	0.3	1.0	%/1 kHrs

ELECTRICAL CHARACTERISTICS (VI - VO = 5.0 V: IO = 0.1 A. T. I = TIOW to Think (Note 7), unless otherwise noted.)

7. T_{low} to $T_{high} = 0^{\circ}$ to +125°C for LM317MA T_{low} to $T_{high} = -40^{\circ}$ to +125°C for LM317MAB, NCV317MAB. 8. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

 C_{Adj}, when used, is connected between the adjustment pin and ground.
 Thermal characteristics are not subject to production test.
 Since Long-Term Stability cannot be measured on each device before shipment, this specification is an engineering estimate of average stability from lot-to-lot.

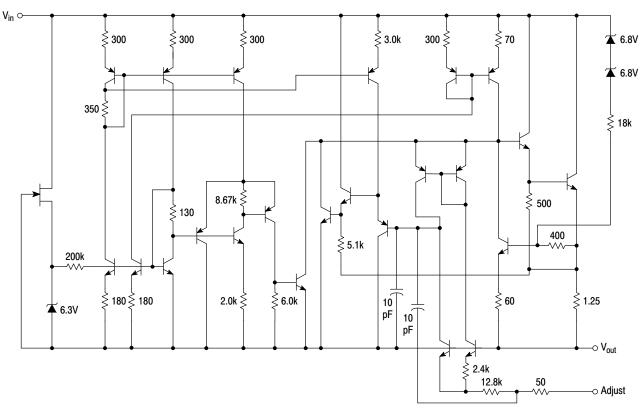
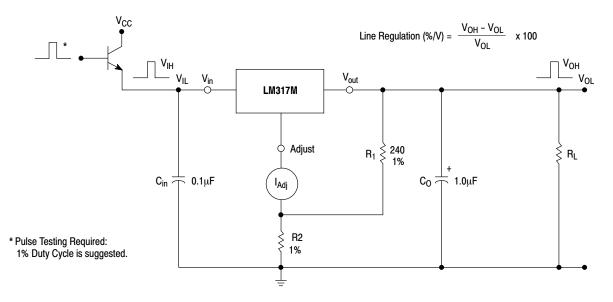
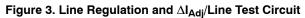
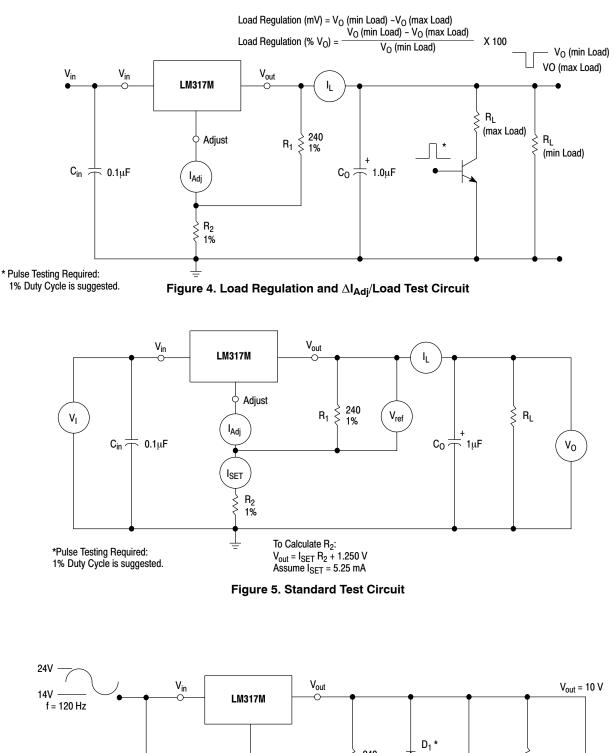
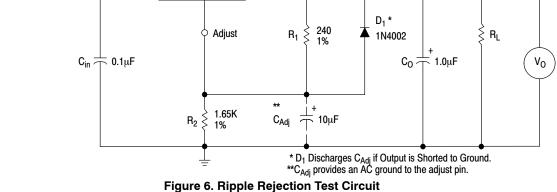


Figure 2. Representative Schematic Diagram

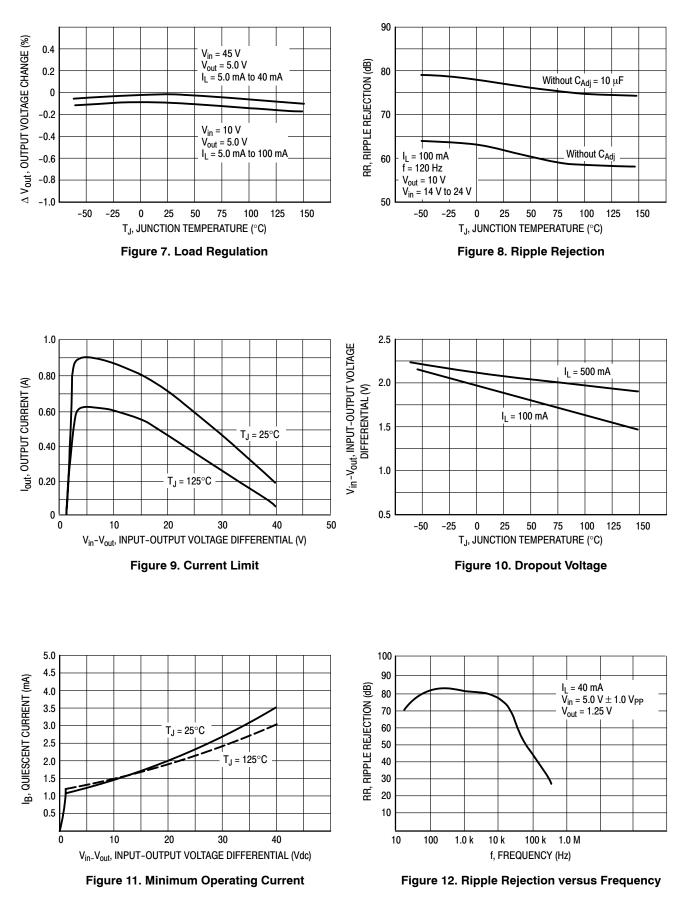


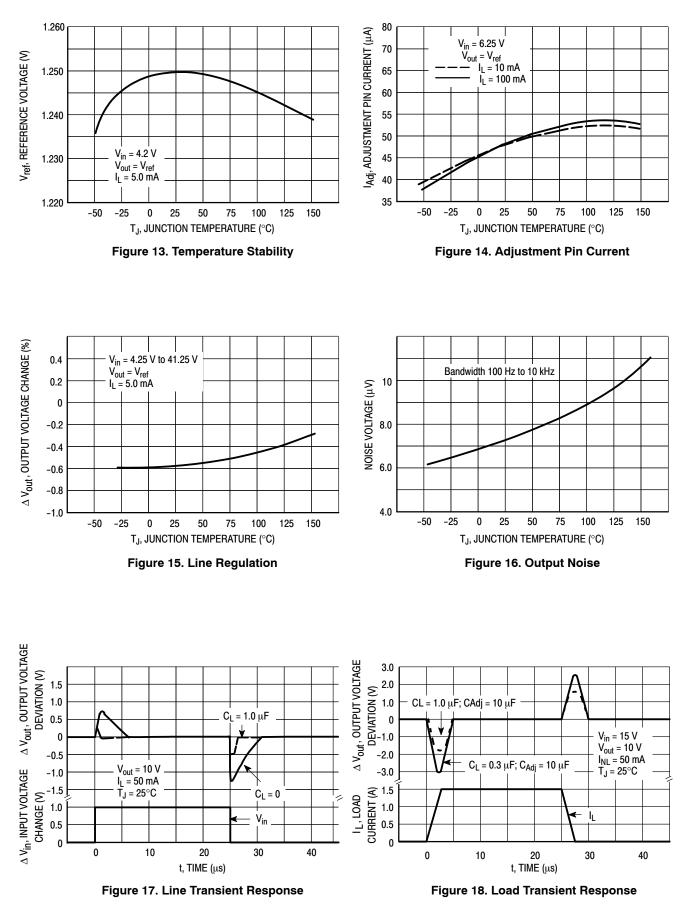






www.onsemi.com 5





APPLICATIONS INFORMATION

Basic Circuit Operation

The LM317M is a three-terminal floating regulator. In operation, the LM317M develops and maintains a nominal 1.25 V reference (V_{ref}) between its output and adjustment terminals. This reference voltage is converted to a programming current (I_{PROG}) by R_1 (see Figure 19), and this constant current flows through R_2 to ground. The regulated output voltage is given by:

$$V_{out} = V_{ref} \left(1 + \frac{R_2}{R_1} \right) + I_{Adj} R_2$$

Since the current from the terminal (I_{Adj}) represents an error term in the equation, the LM317M was designed to control I_{Adj} to less than 100 µA and keep it constant. To do this, all quiescent operating current is returned to the output terminal. This imposes the requirement for a minimum load current. If the load current is less than this minimum, the output voltage will rise.

Since the LM317M is a floating regulator, it is only the voltage differential across the circuit which is important to performance, and operation at high voltages with respect to ground is possible.

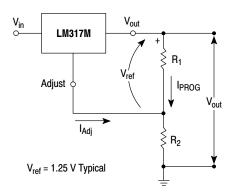


Figure 19. Basic Circuit Configuration

Load Regulation

The LM317M is capable of providing extremely good load regulation, but a few precautions are needed to obtain maximum performance. For best performance, the programming resistor (R_1) should be connected as close to the regulator as possible to minimize line drops which effectively appear in series with the reference, thereby degrading regulation. The ground end of R_2 can be returned near the load ground to provide remote ground sensing and improve load regulation.

External Capacitors

A 0.1 μF disc or 1.0 μF tantalum input bypass capacitor (C_{in}) is recommended to reduce the sensitivity to input line impedance.

The adjustment terminal may be bypassed to ground to improve ripple rejection. This capacitor (C_{Adj}) prevents ripple from being amplified as the output voltage is increased. A 10 μ F capacitor should improve ripple rejection about 15 dB at 120 Hz in a 10 V application.

Although the LM317M is stable with no output capacitance, like any feedback circuit, certain values of external capacitance can cause excessive ringing. An output capacitance (C_0) in the form of a 1.0 μ F tantalum or 25 μ F aluminum electrolytic capacitor on the output swamps this effect and insures stability.

Protection Diodes

When external capacitors are used with any IC regulator it is sometimes necessary to add protection diodes to prevent the capacitors from discharging through low current points into the regulator.

Figure 20 shows the LM317M with the recommended protection diodes for output voltages in excess of 25 V or high capacitance values ($C_O > 25 \ \mu\text{F}$, $C_{Adj} > 5.0 \ \mu\text{F}$). Diode D_1 prevents C_O from discharging thru the IC during an input short circuit. Diode D_2 protects against capacitor C_{Adj} discharging through the IC during an output short circuit. The combination of diodes D_1 and D_2 prevents C_{Adj} from discharging through the IC during an input short circuit.

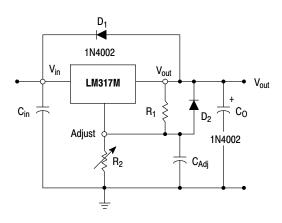
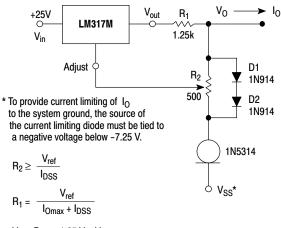


Figure 20. Voltage Regulator with Protection Diodes



 $V_0 < P_{OV} + 1.25 V + V_{SS}$ $I_{Lmin} - I_P < I_O < 500 \text{ mA} - I_P$ As shown O < $I_O < 495 \text{ mA}$

100

90

80

70

60

50

40

0

Free Air

Mounted

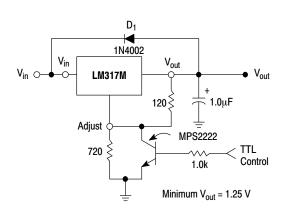
Vertically

5.0

Minimum

Size Pad

Figure 21. Adjustable Current Limiter



D1 protects the device during an input short circuit.

Figure 22. 5 V Electronic Shutdown Regulator

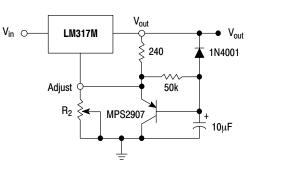


Figure 23. Slow Turn-On Regulator

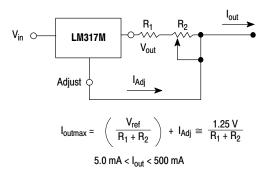
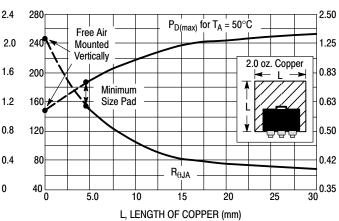
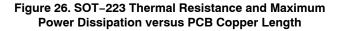
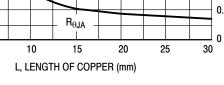


Figure 24. Current Regulator



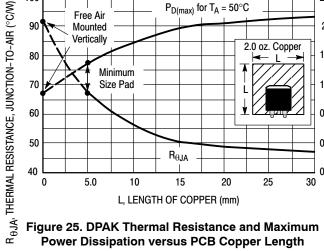




۷

 $P_{D(max)}$ for $T_A = 50^{\circ}C$

2.0 oz. Copper

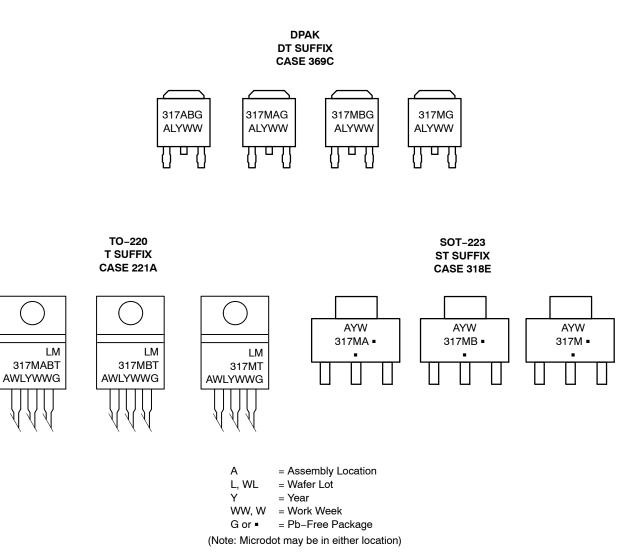


ORDERING INFORMATION

Device	Output Voltage Tolerance	Operating Temperature Range	Package	Shipping [†]
LM317MABDTG		T _{.1} = −40°C to 125°C	DPAK (Pb-Free)	75 Units / Rail
LM317MABDTRKG			DPAK	2500 / Tape & Reel
NCV317MABDTRKG*			(Pb-Free)	
NCV317MABSTT3G*	2%		SOT-223 (Pb-Free)	4000 / Tape & Reel
LM317MABTG			TO-220 (Pb-Free)	50 Units / Rail
LM317MADTRKG		$T_J = 0^{\circ}C$ to $125^{\circ}C$	DPAK (Pb-Free)	2500 / Tape & Reel
LM317MBDTG		T 1001 1000	DPAK	75 Units / Rail
NCV317MBDTG*			(Pb-Free)	
LM317MBDTRKG			DPAK	2500 / Tape & Reel
NCV317MBDTRKG*	-		(Pb-Free)	
LM317MBSTT3G	-	$T_J = -40^{\circ}C$ to $125^{\circ}C$	SOT-223	4000 / Tape & Reel
NCV317MBSTT3G*	-	·	(Pb-Free)	
LM317MBTG	-		TO-220	50 Units / Rail
NCV317MBTG*	4%		(Pb-Free)	
LM317MDTG			DPAK (Pb–Free)	75 Units / Rail
LM317MDTRKG	1	T 000 1: 10500	DPAK (Pb–Free)	2500 / Tape & Reel
LM317MSTT3G		$T_J = 0^{\circ}C$ to $125^{\circ}C$	SOT-223 (Pb-Free)	4000 / Tape & Reel
LM317MTG			TO-220 (Pb-Free)	50 Units / Rail

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.
 *NCV devices: T_{low} = -40°C, T_{high} = +125°C. Guaranteed by design. NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

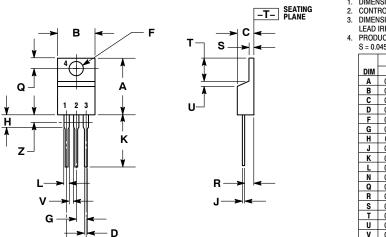
MARKING DIAGRAMS



PACKAGE DIMENSIONS

TO-220, SINGLE GAUGE CASE 221AB

ISSUE A

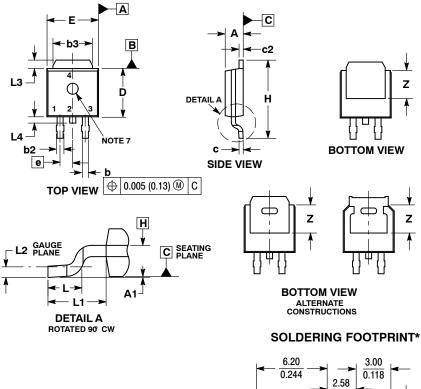


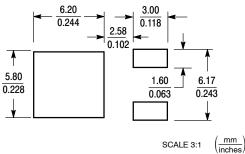
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCHES. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED. 4. PRODUCT SHIPPED PRIOR TO 2008 HAD DIMENSIONS S = 0.045 0.055 INCHES (1.143 1.397 MM)

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
ſ	0.018	0.025	0.46	0.64
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.020	0.024	0.508	0.61
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Ζ		0.080		2.04

PACKAGE DIMENSIONS

DPAK **DT SUFFIX** CASE 369C **ISSUE F**





*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

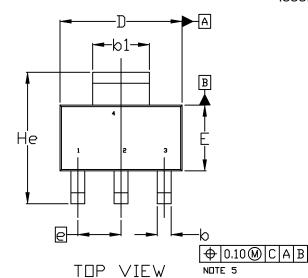
- NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
 THERMAL PAD CONTOUR OPTIONAL WITHIN DI-MENSIONS b AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
 DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
 DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
 OPTIONAL MOLD FEATURE.

•	OFIN	JINAL WOLD FEA	IUNE.
		INCHES	MILLIME.

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
С	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
Е	0.250	0.265	6.35	6.73
е	0.090	BSC	2.29	BSC
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114	REF	2.90	REF
L2	0.020	BSC	0.51	BSC
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Ζ	0.155		3.93	

PACKAGE DIMENSIONS

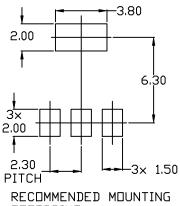
SOT-223 (TO-261) ST SUFFIX CASE 318E-04 **ISSUE R**



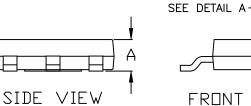
NDTES:

- DIMENSIONING AND TOLERANCING PER 1. ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSIONS D & E DO NOT INCLUDE MOLD з. FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
- DATUMS A AND B ARE DETERMINED AT DATUM H. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST 4. 5.
- PDINT OF THE PACKAGE BODY.
- POSITIONAL TOLERANCE APPLIES TO DIMENSIONS 6 AND 61. 6.

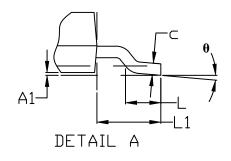
	MILLIMETERS					
DIM	MIN.	NDM.	MAX.			
Α	1.50	1.63	1.75			
A1	0.02	0.06	0.10			
b	0.60	0.75	0.89			
b1	2.90	3.06	3.20			
С	0.24	0.29	0.35			
D	6.30	6.50	6.70			
E	3.30	3.50	3.70			
e		5.30 B2C	:			
L	0.20					
L1	1.50	1.75	2.00			
He	6.70	7.00	7.30			
θ	0*		10*			



FOOTPRINT







Η

0.10 C

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or the rights of others. ON Semiconductor and the support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor handles or unauthorized date application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and listributors harmless against all claims, costs, damages, and expenses, and reasonable attorney tees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that

Phone: 421 33 790 2910

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

 \Diamond

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: NCV317MBSTT3G NCV317MBTG